BU2720DF

GENERAL DESCRIPTION

High voltage, high-speed switching npn transistor with integrated damper diode in a plastic full-pack envelope. Intended for use in horizontal deflection circuits of colour television receivers up to 16 kHz. Designed to withstand V_{CES} pulses up to 1700V.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1700	V
V _{CEO}	Collector-emitter voltage (open base)		-	825	V
	Collector current (DC)		-	10	Α
1.17	Collector current peak value		-	25	Α
P _{tot}	Total power dissipation	$T_{hs} \le 25 \degree C$	-	45	W
I _{CM} P _{tot} V _{CEsat}	Collector-emitter saturation voltage	T _{hs} ≤ 25 °C I _C = 5.5 A; I _B = 1.38 A	-	1.0	V
I _{Csat}	Collector saturation current		5.5	-	A
ts	Storage time	$I_{CM} = 5.5 \text{ A}; I_{B(end)} = 1.2 \text{ A}$	7.4	8.5	μs

PINNING - SOT199

PIN CONFIGURATION

SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CESM}	Collector-emitter voltage peak value	$V_{BE} = 0 V$	-	1700	V
V _{CEO}	Collector-emitter voltage (open base)		-	825	V
I _C	Collector current (DC)		-	10	A
I _{CM}	Collector current peak value		-	25	A
I _B	Base current (DC)		-	10	A
I _{BM}	Base current peak value		-	20	A
-I _{B(AV)}	Reverse base current	average over any 20 ms period	-	150	mA
-I _{BM}	Reverse base current peak value ¹		-	20	A
P _{tot}	Total power dissipation	$T_{hs} \leq 25 \degree C$	-	45	W
P _{tot} T _{stg}	Storage temperature		-65	150	°C
$ T_j^{-1} $	Junction temperature		-	150	°C

ESD LIMITING VALUES

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _c	Electrostatic discharge capacitor voltage	Human body model (250 pF, 1.5 kΩ)	-	10	kV

¹ Turn-off current.

BU2720DF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	Junction to heatsink	without heatsink compound	-	3.7	K/W
R _{th j-hs}	Junction to heatsink	with heatsink compound	-	2.8	K/W
R _{th j-a}	Junction to ambient	in free air	35	-	K/W

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	Repetitive peak voltage from all three terminals to external heatsink	$R.H. \leq 65~\%$; clean and dustfree	-		2500	V
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	-	22	-	pF

STATIC CHARACTERISTICS

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	Collector cut-off current ²		-	-	1.0	mĄ
ICES		V _{BE} = 0 V; V _{CE} = V _{CESMmax} ; T _i = 125 °C	-	-	2.0	mA
I _{EBO}	Emitter cut-off current	$V_{EB} = 7.5 \text{ V}; I_{C} = 0 \text{ A}$	85	-	150	mA
I _{EBO} BV _{EBO}	Emitter-base breakdown voltage	$I_{B} = 600 \text{ mA}$	7.5	13.5	-	V
R _{BE}	Base-emitter resistance	$V_{EB} = 7.5 V$		65		Ω
V _{CEsat}	Collector-emitter saturation voltage	$I_{\rm C} = 5.5 \text{ A}; I_{\rm B} = 1.38 \text{ A}$	-	-	1.0	V
V _{BEsat}	Base-emitter saturation voltage	$I_{\rm C} = 5.5 \text{A}; I_{\rm B} = 1.38 \text{A}$	0.82	0.9	1.0	V
V _F	Diode forward voltage	$I_{\rm F} = 5.5 \rm A$		1.6	00	V
h _{FE}	DC current gain	$I_{\rm C} = 1 \text{ A}; V_{\rm CE} = 5 \text{ V}$	14	19	26	
h _{FE}		$I_{C} = 5.5 \text{ A}; V_{CE} = 1 \text{ V}$	4	5.5	7.5	

DYNAMIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
		$\begin{array}{l} I_{CM} = 5.5 \text{ A}; \ L_{C} = 750 \ \mu\text{H}; \\ C_{fb} = 15.5 \ \text{nF}; \ V_{CC} = 125 \ \text{V}; \\ I_{B(end)} = 1.2 \ \text{A}; \ L_{B} = 6 \ \mu\text{H}; \ \text{-V}_{BB} = 4 \ \text{V}; \\ \text{-I}_{BM} = I_{CM} / 2 \end{array}$			
t _s t _f	Turn-off storage time Turn-off fall time		7.4 0.7	8.5 0.9	μs μs

2

² Measured with half sine-wave voltage (curve tracer).

BU2720DF



BU2720DF



BU2720DF



Product specification

BU2720DF

MECHANICAL DATA



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

BU2720DF

DEFINITIONS

Data sheet status				
Objective specification	Dbjective specification This data sheet contains target or goal specifications for product development.			
Preliminary specification	Preliminary specification This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
or more of the limiting val operation of the device at	Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.			
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
© Philips Electronics N.V. 1995				
All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.				

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.